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Biography

C U R R I C U L U M V I T A E

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Professor , Doctor

PERMANENT

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PERSONAL: Born September 15, 1941, Bolnisi, Republic of Georgia

Nationality : Azerbaijanian

EDUCATION: Baku State University , Physics Department , 1958-1963

Post-Graduate Studentship - Physico-Technical Institute, USSR Academy of Sciences , Leningrad , 1968-1972

Cand. Sci. Thesis: Physico-Technical Institute, USSR Academy of Sciences , 1972

Thesis Title: " Vibrational Spectrum and Absorption Edge of Solid Solutions on the Basis of InSb "

Doctor Sci. Thesis: Institute of Physics , Azerbaijan Academy of Sciences , 1986

Thesis Title: " Spectroscopy of Optical Vibrational States of A³B⁶-Type Anisotropic Semiconductive Crystals "

PROFESSIONAL

POSITIONS: Research Assistant , Physics Department ,
Baku State University , 1964-1967

Post-Graduate Student , Physico-Technical Institute ,
USSR Academy of Sciences , Leningrad , 1968-1972

Teacher, Senior Teacher , Associate-Professor , Professor ,
Physics Department , Baku State University , 1972-1991

Vice-Dean, Physics Department , Baku State University ,
1989-1991

Visiting Professor , Physics Department ,
Middle East Technical University , Ankara , 1992 - present time

SCIENTIFIC WORK

IN THE FOREIGN

UNIVERSITIES: Institute of Physics II - Solid State Physics ,
University of Regensburg , Regensburg , Germany , 1984

Wihuri Physical Laboratory , University of Turku ,
Turku , Finland , 1991

TOTAL NUMBER OF INTERNATIONAL PUBLICATIONS

(Web of Science, SCI) : **366 papers**

Research Areas

Intensive Article 2: Electronic Structure, Electric, Magnetic and Optical Properties

Advising Theses

HASANLI N., Low temperature thermoluminescence study of some ternary and quaternary layered structured semiconductors, Doctorate, S.DELİCE(Student), 2016

HASANLI N., Optical and electrical characterization of Ga_{0.75}In_{0.25}Se layered single crystals, Doctorate, M.İşık(Student), 2013

HASANLI N., Optical and electrical transport properties of some quaternary thallium dichalcogenides, Doctorate, İ.Güler(Student), 2011

HASANLI N., Thermally stimulated current study of traps distribution in TiGaSeS layered single crystals, Postgraduate, H.Nasser(Student), 2010

HASANLI N., Optical properties of some quaternary thallium chalcogenides, Doctorate, K.Gökşen(Student), 2008

HASANLI N., Low temperature photoluminescence study in GaS-GaSe layered crystals., Postgraduate, K.Gökşen(Student), 2002

Published journal articles indexed by SCI, SSCI, and AHCI

- I. **Thermoluminescence dose response and kinetic parameters of Gd-doped ZnO nanoparticles**
Isik M., Yildirim T., Guner M., Hasanlı N.
PHYSICA SCRIPTA, vol.99, no.7, 2024 (SCI-Expanded)
- II. **Revealing photoluminescence and nonlinear optical absorption characteristics of PbMo_{0.75}W_{0.25}O₄ single crystal for optical limiting applications**
Doğan A., Karatay A., Isik M., Yıldız E., Hasanlı N., Elmalı A.
Physica Scripta, vol.99, no.5, 2024 (SCI-Expanded)
- III. **Temperature-dependent tuning of band gap of Fe₃O₄ nanoparticles for optoelectronic applications**

Delice S., Isik M., HASANLI N.

Chemical Physics Letters, vol.840, 2024 (SCI-Expanded)

- IV. **Revealing defect centers in PbWO_4 single crystals using thermally stimulated current measurements**
Isik M., HASANLI N.
JOURNAL OF APPLIED PHYSICS, vol.135, no.8, 2024 (SCI-Expanded)
- V. **Characterization of linear and nonlinear optical properties of $\text{NaBi}(\text{WO}_4)_2$ crystal by spectroscopic ellipsometry**
Isik M., Guler I., HASANLI N.
Optical Materials, vol.148, 2024 (SCI-Expanded)
- VI. **Growth and optical properties of $(\text{Na}_{0.5}\text{Bi}_{0.5})(\text{Mo}_{1-x}\text{W}_x)\text{O}_4$ ($x = 0.25$) single crystal: a potential candidate for optoelectronic devices**
Guler I., Isik M., HASANLI N.
Optical and Quantum Electronics, vol.56, no.1, 2024 (SCI-Expanded)
- VII. **Exploring the linear and nonlinear optical behavior of $(\text{TlInS}_2)_{0.75}(\text{TlInSe}_2)_{0.25}$: Insights from ellipsometry measurements**
Isik M., Guler I., Hasanli N.
Physica B: Condensed Matter, vol.669, 2023 (SCI-Expanded)
- VIII. **Temperature-dependent optical properties of TiO_2 nanoparticles: a study of band gap evolution**
Isik M., Delice S., HASANLI N.
Optical and Quantum Electronics, vol.55, no.10, 2023 (SCI-Expanded)
- IX. **Growth and temperature-tuned band gap characteristics of $\text{LiGd}(\text{MoO}_4)_2$ single crystals for optoelectronic applications**
Delice S., Isik M., HASANLI N., Darvishov N., Bagiev V.
Ceramics International, vol.49, no.15, pp.25840-25847, 2023 (SCI-Expanded)
- X. **Temperature-dependent current-voltage characteristics of $\text{p-GaSe}_{0.75}\text{S}_{0.25}/\text{n-Si}$ heterojunction**
Isik M., Surucu O., HASANLI N.
Applied Physics A: Materials Science and Processing, vol.129, no.8, 2023 (SCI-Expanded)
- XI. **Tunable nonlinear absorption and optical limiting behavior of $\text{NaBi}(\text{Mo}_x\text{W}_{1-x}\text{O}_4)_2$ single crystals with ratio of Molybdenum/Tungsten**
PEPE Y., YILDIZ E., Isik M., KARATAY A., Gasanly N., ELMALI A.
PHYSICA SCRIPTA, vol.98, no.7, 2023 (SCI-Expanded)
- XII. **Optical characterization of $(\text{TlInS}_2)_{0.5}(\text{TlInSe}_2)_{0.5}$ crystal by ellipsometry: linear and optical constants for optoelectronic devices**
Guler I., Isik M., HASANLI N.
Journal of Materials Science: Materials in Electronics, vol.34, no.17, 2023 (SCI-Expanded)
- XIII. **Spectroscopic ellipsometry studies of optical properties of $\text{TlIn}(\text{S}_{0.25}\text{Se}_{0.75})_2$ crystal**
Guler I., Isik M., HASANLI N.
Applied Physics A: Materials Science and Processing, vol.129, no.6, 2023 (SCI-Expanded)
- XIV. **Temperature dependence of band gap of CeO_2 nanoparticle photocatalysts**
Isik M., Delice S., HASANLI N.
Physica E: Low-Dimensional Systems and Nanostructures, vol.150, 2023 (SCI-Expanded)
- XV. **Excitation wavelength dependent nonlinear absorption mechanisms and optical limiting properties of $\text{Bi}_{12}\text{SiO}_{20}$ single crystal**
Doğan A., KARATAY A., Isik M., PEPE Y., HASANLI N., ELMALI A.
Optical Materials, vol.140, 2023 (SCI-Expanded)
- XVI. **Growth and characterization of $\text{NaBi}(\text{Mo}_{0.5}\text{W}_{0.5}\text{O}_4)_2$ single crystal: A promising material for optoelectronic applications**
Isik M., Guler I., HASANLI N.
Materials Science in Semiconductor Processing, vol.156, 2023 (SCI-Expanded)
- XVII. **Growth and characterization of $\text{PbMo}_{0.75}\text{W}_{0.25}\text{O}_4$ single crystal: A promising material for optical**

applications

Isik M., HASANLI N., Darvishov N., Bagiev V.

Materials Chemistry and Physics, vol.296, 2023 (SCI-Expanded)

- XVIII. Growth and temperature tuned band gap characteristics of NaBi(MoO₄)₂ single crystal**
Isik M., Guler I., Hasanli N.
Physica Scripta, vol.98, no.2, 2023 (SCI-Expanded)
- XIX. Linear and nonlinear optical properties of Bi₁₂GeO₂₀ single crystal for optoelectronic applications**
Isik M., HASANLI N.
MATERIALS SCIENCE IN SEMICONDUCTOR PROCESSING, vol.153, 2023 (SCI-Expanded)
- XX. Wavelength dependence of the nonlinear absorption performance and optical limiting in Bi₁₂TiO₂₀ single crystal**
PEPE Y., Isik M., KARATAY A., HASANLI N., ELMALI A.
Journal of Luminescence, vol.253, 2023 (SCI-Expanded)
- XXI. Structural and optical properties of (TlInS₂)_{0.75}(TlInSe₂)_{0.25} thin films deposited by thermal evaporation**
Guler I., Isik M., HASANLI N.
Journal of Materials Science: Materials in Electronics, vol.34, no.3, 2023 (SCI-Expanded)
- XXII. Shallow trapping centers in Bi₁₂GeO₂₀ single crystals by thermally stimulated current measurements**
Delice S., Isik M., HASANLI N.
Materials Today Communications, vol.33, 2022 (SCI-Expanded)
- XXIII. Investigation of linear and nonlinear optical properties of PbWO₄ single crystal**
Delice S., Isik M., HASANLI N.
Optical Materials, vol.133, 2022 (SCI-Expanded)
- XXIV. Temperature effects on optical characteristics of thermally evaporated CuSbSe₂ thin films for solar cell applications**
Surucu O., Isik M., Terlemezoglu M., Bektas T., Hasanli N., Parlak M.
Optical Materials, vol.133, 2022 (SCI-Expanded)
- XXV. The role of defects on the transition from saturable absorption to nonlinear absorption of Bi₁₂GeO₂₀ single crystal under increasing laser excitation**
PEPE Y., Isik M., KARATAY A., YILDIZ E., HASANLI N., ELMALI A.
Journal of Luminescence, vol.251, 2022 (SCI-Expanded)
- XXVI. Nonlinear optical absorption characteristics of PbMoO₄ single crystal for optical limiter applications**
PEPE Y., Isik M., KARATAY A., HASANLI N., ELMALI A.
Optical Materials, vol.133, 2022 (SCI-Expanded)
- XXVII. Structural, morphological and temperature-tuned bandgap characteristics of CuS nano-flake thin films**
Isik M., Terlemezoglu M., Hasanli N., Parlak M.
Physica E: Low-Dimensional Systems and Nanostructures, vol.144, 2022 (SCI-Expanded)
- XXVIII. Linear and nonlinear optical characteristics of PbMoO₄ single crystal for optoelectronic applications**
Delice S., Isik M., Hasanli N.
Journal of Materials Science: Materials in Electronics, vol.33, no.28, pp.22281-22290, 2022 (SCI-Expanded)
- XXIX. Linear and nonlinear optical characteristics of Bi₁₂SiO₂₀ single crystals**
Isik M., HASANLI N.
Optical Materials, vol.131, 2022 (SCI-Expanded)
- XXX. Spectroscopic ellipsometry characterization of PbWO₄ single crystals**
Delice S., Isik M., HASANLI N., Darvishov N., Bagiev V.
Optical Materials, vol.131, 2022 (SCI-Expanded)
- XXXI. Temperature-tuned optical bandgap of Al-doped ZnO spin coated nanostructured thin films**
Isik M., HASANLI N.
Materials Letters, vol.321, 2022 (SCI-Expanded)

- XXXII. **A method to predict temperature derivatives of the bulk modulus: A case study for HfB₂**
Özkan H., Delice S., HASANLI N.
Physica Scripta, vol.97, no.8, 2022 (SCI-Expanded)
- XXXIII. **Investigation of optical characteristics of PbMoO₄ single crystals by spectroscopic ellipsometry**
Delice S., Isik M., HASANLI N., Darvishov N., Bagiev V.
Optik, vol.262, 2022 (SCI-Expanded)
- XXXIV. **Study of the structural and optical properties of thallium gallium disulfide (TlGaS₂) thin films grown via thermal evaporation**
Isik M., KARATAY A., Ech-Chergui A., HASANLI N.
Physica Scripta, vol.97, no.7, 2022 (SCI-Expanded)
- XXXV. **Thermoluminescence characteristics of GaSe and Ga₂Se₃ single crystals**
Isik M., SARIGÜL N., HASANLI N.
Journal of Luminescence, vol.246, 2022 (SCI-Expanded)
- XXXVI. **Temperature dependent bandgap in NaBi(WO₄)₂ single crystals**
Isik M., HASANLI N., Darvishov N., Bagiev V.
Optik, vol.258, 2022 (SCI-Expanded)
- XXXVII. **Thermoluminescence properties and trapping parameters of TlGaS₂ single crystals**
Delice S., Isik M., HASANLI N.
Journal of Luminescence, vol.244, 2022 (SCI-Expanded)
- XXXVIII. **Effect of temperature on band gap of PbWO₄ single crystals grown by Czochralski method**
Isik M., Hasanlı N., Darvishov N. H., Bagiev V. E.
PHYSICA SCRIPTA, vol.97, no.4, 2022 (SCI-Expanded)
- XXXIX. **Structural and temperature-tuned band gap energy characteristics of PbMoO₄ single crystals**
Isik M., HASANLI N., Darvishov N., Bagiev V.
Optical Materials, vol.126, 2022 (SCI-Expanded)
- XL. **Determination of mechanical properties of Bi₁₂TiO₂₀ crystals by nanoindentation**
Isik M., HASANLI N., Rustamov F. A.
MATERIALS SCIENCE IN SEMICONDUCTOR PROCESSING, vol.140, 2022 (SCI-Expanded)
- XLI. **Structural and optical characteristics of thermally evaporated TlGaSe₂ thin films**
Isik M., KARATAY A., HASANLI N.
Optical Materials, vol.124, 2022 (SCI-Expanded)
- XLII. **Temperature-dependent optical characteristics of sputtered NiO thin films**
Terlemezoglu M., Surucu O., Isik M., Hasanli N., Parlak M.
APPLIED PHYSICS A-MATERIALS SCIENCE & PROCESSING, vol.128, no.1, 2022 (SCI-Expanded)
- XLIII. **Defect assisted nonlinear absorption and optical limiting in amorphous TlGaS₂(1-x)Se₂(x) (0 ≤ x ≤ 1) thin films**
ÜNLÜ B. A., KARATAY A., Yildiz E. A., Dincbay T., ÜNVER H., Gasanly N., ELMALI A.
JOURNAL OF LUMINESCENCE, vol.241, 2022 (SCI-Expanded)
- XLIV. **Investigation of defect levels in Bi₁₂SiO₂₀ single crystals by thermally stimulated current measurements**
Isik M., Delice S., HASANLI N.
PHYSICA SCRIPTA, vol.96, no.12, 2021 (SCI-Expanded)
- XLV. **Trapping centers in Bi₁₂TiO₂₀ single crystals by thermally stimulated current**
Isik M., Delice S., HASANLI N., Darvishov N., Bagiev V.
Optical Materials, vol.122, 2021 (SCI-Expanded)
- XLVI. **Experimental and theoretical investigation of the mechanical characteristics of sillenite compound: Bi₁₂GeO₂₀**
SÜRÜCÜ G., Isik M., Gencer A., HASANLI N.
Journal of Alloys and Compounds, vol.882, 2021 (SCI-Expanded)
- XLVII. **Effect of thallium (Tl) substitution for indium (In) on ellipsometric characteristics of TlInSe₂ single crystals**

- Isik M., HASANLI N.
Materials Science in Semiconductor Processing, vol.134, 2021 (SCI-Expanded)
- XLVIII. **The effect of Zn concentration on the structural and optical properties of Cd_{1-x}Zn_xS nanostructured thin films**
Isik M., Terlemezoglu M., Isik S., Erturk K., HASANLI N.
JOURNAL OF MATERIALS SCIENCE-MATERIALS IN ELECTRONICS, vol.32, no.20, pp.25225-25233, 2021 (SCI-Expanded)
- XLIX. **Evaluation of mechanical properties of Bi₁₂SiO₂₀ sillenite using first principles and nanoindentation**
Isik M., Sürücü G., Gencer A., Hasanlı N.
PHILOSOPHICAL MAGAZINE, vol.101, no.20, pp.2200-2215, 2021 (SCI-Expanded)
- L. **Electronic, optical and thermodynamic characteristics of Bi₁₂SiO₂₀ sillenite: First principle calculations**
Isik M., SÜRÜCÜ G., Gencer A., HASANLI N.
Materials Chemistry and Physics, vol.267, 2021 (SCI-Expanded)
- LI. **First principles study of Bi₁₂GeO₂₀: Electronic, optical and thermodynamic characterizations**
Isik M., Sürücü G., Gencer A., Hasanlı N.
Materials Today Communications, vol.27, 2021 (SCI-Expanded)
- LII. **Structural and temperature-tuned bandgap characteristics of thermally evaporated beta-In₂S₃ thin films**
Surucu O., Isik M., Terlemezoglu M., Hasanlı N., Parlak M.
JOURNAL OF MATERIALS SCIENCE-MATERIALS IN ELECTRONICS, vol.32, no.12, pp.15851-15856, 2021 (SCI-Expanded)
- LIII. **Defect characterization in Bi₁₂GeO₂₀ single crystals by thermoluminescence**
Delice S., Isik M., SARIGÜL N., HASANLI N.
JOURNAL OF LUMINESCENCE, vol.233, 2021 (SCI-Expanded)
- LIV. **Investigation of traps distribution in GaS single crystals by thermally stimulated current measurements**
Delice S., Isik M., HASANLI N.
MATERIALS SCIENCE IN SEMICONDUCTOR PROCESSING, vol.125, 2021 (SCI-Expanded)
- LV. **Optical and structural characteristics of electrodeposited Cd 1-xZn_xS nanostructured thin films**
Erturk K., Isik M., Terlemezoglu M., HASANLI N.
Optical Materials, vol.114, 2021 (SCI-Expanded)
- LVI. **Spectroscopic ellipsometry study of Bi₁₂TiO₂₀ single crystals**
Isik M., Hasanlı N., Darvishov N. H., Bagiev V. E.
JOURNAL OF MATERIALS SCIENCE-MATERIALS IN ELECTRONICS, vol.32, no.6, pp.7019-7025, 2021 (SCI-Expanded)
- LVII. **Temperature effects on optical characteristics of CdSe thin films**
Gullu H. H., Isik M., Surucu O., Hasanlı N., Parlak M.
MATERIALS SCIENCE IN SEMICONDUCTOR PROCESSING, vol.123, 2021 (SCI-Expanded)
- LVIII. **Structural and optical properties of thermally evaporated (GaSe)_{0.75}-(GaS)_{0.25} thin films**
Isik M., Emir C., HASANLI N.
OPTIK, vol.230, 2021 (SCI-Expanded)
- LIX. **Observation of in situ enhanced crystallization, negative resistance effect and photosensitivity in Ti₂InGaSe₄ crystals**
Qasrawi A. F., Irshaid T. M. A., HASANLI N.
MATERIALS SCIENCE IN SEMICONDUCTOR PROCESSING, vol.122, 2021 (SCI-Expanded)
- LX. **Optical and Nanomechanical Properties of Ga₍₂₎Se₍₃₎ Single Crystals and Thin Films**
Işık M., Emir C., Gullu H. H., Gasanlı N.
JOM, vol.73, no.2, pp.558-565, 2021 (SCI-Expanded)
- LXI. **Temperature-dependent optical characteristics of sputtered Ga-doped ZnO thin films**
Gullu H. H., Isik M., Hasanlı N., Parlak M.

MATERIALS SCIENCE AND ENGINEERING B-ADVANCED FUNCTIONAL SOLID-STATE MATERIALS, vol.263, 2021 (SCI-Expanded)

- LXII. **Temperature-tuned bandgap characteristics of Bi₁₂TiO₂₀ sillenite single crystals**
Isik M., Delice S., HASANLI N., Darvishov N. H., Bagiev V. E.
JOURNAL OF MATERIALS SCIENCE-MATERIALS IN ELECTRONICS, vol.32, no.1, pp.1316-1322, 2021 (SCI-Expanded)
- LXIII. **Optical characteristics of Bi₁₂SiO₂₀ single crystals by spectroscopic ellipsometry**
Isik M., Delice S., Nasser H., HASANLI N., Darvishov N. H., Bagiev V. E.
MATERIALS SCIENCE IN SEMICONDUCTOR PROCESSING, vol.120, 2020 (SCI-Expanded)
- LXIV. **Temperature-tuned band gap properties of MoS₂ thin films**
Surucu O., Isik M., Gasanly N., Terlemezoglu M., Parlak M.
MATERIALS LETTERS, vol.275, 2020 (SCI-Expanded)
- LXV. **TL and OSL studies on gallium sulfide (GaS) single crystals**
Isik M., YÜKSEL M., TOPAKSU M., Gasanly N.
JOURNAL OF LUMINESCENCE, vol.225, 2020 (SCI-Expanded)
- LXVI. **Vibrational modes in (TlGaS₂)_x-(TlGaSe₂)_(1-x) mixed crystals by Raman measurements: compositional dependence of the mode frequencies and line-shapes**
Isik M., Terlemezoglu M., HASANLI N., Babayeva R. F.
JOURNAL OF MATERIALS SCIENCE-MATERIALS IN ELECTRONICS, vol.31, no.17, pp.14330-14335, 2020 (SCI-Expanded)
- LXVII. **Investigation of structural and optical characteristics of thermally evaporated Ga₂Se₃ thin films**
Isik M., Gasanly N.
VACUUM, vol.179, 2020 (SCI-Expanded)
- LXVIII. **Temperature dependent band gap in SnS_{2x}Se_(2-2x) (x=0.5) thin films**
Delice S., Isik M., Gullu H. H., Terlemezoglu M., Surucu O. B., Gasanly N., Parlak M.
MATERIALS SCIENCE IN SEMICONDUCTOR PROCESSING, vol.114, 2020 (SCI-Expanded)
- LXIX. **Thermoluminescence characteristics of Bi₁₂SiO₂₀ single crystals**
Isik M., SARIGÜL N., Gasanly N.
JOURNAL OF LUMINESCENCE, vol.224, 2020 (SCI-Expanded)
- LXX. **Structural and temperature-tuned optical characteristics of Bi₁₂GeO₂₀ sillenite crystals**
Delice S., Isik M., Gasanly N., Darvishov N., Bagiev V.
CHINESE JOURNAL OF PHYSICS, vol.66, pp.422-429, 2020 (SCI-Expanded)
- LXXI. **The effect of Ga/In ratio and annealing temperature on the nonlinear absorption behaviors in amorphous TlGa_xIn_(1-x)S₂ (0 ≤ x ≤ 1) chalcogenide thin films**
Ünlü B. A., Karatay A., Yüksek M., Ünver H., Gasanly N., Elmali A.
Optics and Laser Technology, vol.128, 2020 (SCI-Expanded)
- LXXII. **Investigation of band gap energy versus temperature for SnS₂ thin films grown by RF-magnetron sputtering**
Isik M., Gullu H. H., Terlemezoglu M., Surucu O. B., PARLAK M., Gasanly N.
PHYSICA B-CONDENSED MATTER, vol.591, 2020 (SCI-Expanded)
- LXXIII. **Influence of temperature on optical properties of electron-beam-evaporated ZnSe thin film**
Gullu H. H., Isik M., Gasanly N., PARLAK M.
PHYSICA SCRIPTA, vol.95, no.7, 2020 (SCI-Expanded)
- LXXIV. **Investigation of optical properties of Bi₁₂GeO₂₀ sillenite crystals by spectroscopic ellipsometry and Raman spectroscopy**
Isik M., Delice S., Gasanly N., Darvishov N. H., Bagiev V. E.
CERAMICS INTERNATIONAL, vol.46, no.9, pp.12905-12910, 2020 (SCI-Expanded)
- LXXV. **Structural and optical properties of thermally annealed thallium indium disulfide thin films**
Guler I., Gasanly N.
THIN SOLID FILMS, vol.704, 2020 (SCI-Expanded)
- LXXVI. **Temperature-dependent material characterization of CuZnSe₂ thin films**

- Gullu H. H., Surucu O., Terlemezoglu M., Isik M., Ercelebi C., Gasanly N., Parlak M.
THIN SOLID FILMS, vol.701, 2020 (SCI-Expanded)
- LXXXVII. **Temperature -dependent optical and electrical characterization of Cu-Ga-S thin films and their diode characteristics on n-Si**
Gullu H. H., Isik M., Gasanly N., PARLAK M.
OPTIK, vol.208, 2020 (SCI-Expanded)
- LXXXVIII. **Synthesis and temperature-tuned band gap characteristics of magnetron sputtered ZnTe thin films**
Isik M., Gullu H. H., PARLAK M., Gasanly N.
PHYSICA B-CONDENSED MATTER, vol.582, 2020 (SCI-Expanded)
- LXXXIX. **Thermoluminescence characterization of (Ga₂Se₃)(0.25) - (Ga₂S₃)(0.75) single crystal compounds**
Isik M., Guler I., Gasanly N.
MATERIALS SCIENCE IN SEMICONDUCTOR PROCESSING, vol.108, 2020 (SCI-Expanded)
- LXXX. **Optical constants and critical point energies of (AgInSe₂)(0.75)-(In₂Se₃)(0.25) single crystals**
Isik M., Nasser H., Guseinov A., Gasanly N.
JOURNAL OF MATERIALS SCIENCE-MATERIALS IN ELECTRONICS, vol.31, no.6, pp.4702-4707, 2020 (SCI-Expanded)
- LXXXI. **Temperature-tuned band gap characteristics of InSe layered semiconductor single crystals**
Isik M., Gasanly N.
MATERIALS SCIENCE IN SEMICONDUCTOR PROCESSING, vol.107, 2020 (SCI-Expanded)
- LXXXII. **Material and device properties of Si-based Cu_{0.5}Ag_{0.5}InSe₂ thin-film heterojunction diode**
Gullu H. H., Isik M., Delice S., Parlak M., Gasanly N.
JOURNAL OF MATERIALS SCIENCE-MATERIALS IN ELECTRONICS, vol.31, no.2, pp.1566-1573, 2020 (SCI-Expanded)
- LXXXIII. **Temperature-dependent band gap characteristics of Bi₁₂SiO₂₀ single crystals**
Isik M., Delice S., Gasanly N., Darvishov N. H., Bagiev V. E.
JOURNAL OF APPLIED PHYSICS, vol.126, no.24, 2019 (SCI-Expanded)
- LXXXIV. **Study of vibrational modes in (Ga₂S₃)(x) - (Ga₂Se₃)(1-x) mixed crystals by Raman and infrared reflection measurements**
Isik M., Guler I., Gasanly N.
OPTICAL MATERIALS, vol.95, 2019 (SCI-Expanded)
- LXXXV. **The defect state of Yb-doped ZnO nanoparticles using thermoluminescence study**
Hasanlı N., Isik M.
MATERIALS SCIENCE IN SEMICONDUCTOR PROCESSING, vol.100, pp.29-34, 2019 (SCI-Expanded)
- LXXXVI. **Effect of heating rate on thermoluminescence characteristics of Y₂O₃ nanoparticles**
Delice S., Isik M., Hasanlı N.
JOURNAL OF LUMINESCENCE, vol.212, pp.233-237, 2019 (SCI-Expanded)
- LXXXVII. **Temperature dependence of band gaps in sputtered SnSe thin films**
Delice S., Isik M., Gullu H., TERLEMEZOĞLU M., Bayrakli Surucu O., PARLAK M., Gasanly N.
JOURNAL OF PHYSICS AND CHEMISTRY OF SOLIDS, vol.131, pp.22-26, 2019 (SCI-Expanded)
- LXXXVIII. **Traps distribution in sol-gel synthesized ZnO nanoparticles**
Delice S., IŞIK M., Gasanly N.
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- LXXXIX. **Optical properties of (Ga₂Se₃)(0.)(75) - (Ga₂S₃)(0.)(25) single crystals by spectroscopic ellipsometry**
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